HPWT-TH00 HPWT-FH00 HPWT-TL00 HPWT-FL00

SnapLED 70

Technical Data DS09

Using Lumileds' patented solderless clinch technology, SnapLED 70 emitters are attached to a formable metal substrate that offers both styling flexibility and ruggedness unmatched by any other LED assembly.

SnapLED's brilliant luminance, flexibility, and reliability enable distinctive and durable lighting designs for vehicles, signals, and specialty lighting.





Benefits

- Rugged Lighting Products
- Electricity Savings
- Maintenance Savings
- 3-Dimensional Array Design
- Environmental Conformance

Features

- High Luminance
- Low Power Consumption
- Low Thermal Resistance
- Low Profile
- Solderless Mounting Technique
- Formable Substrate
- Meets SAE/ECE/JIS
 Automotive
 - **Color Requirements**
- Packaged in tubes for use with automatic insertion equipment

Typical Applications

- Automotive Lighting
 - Rear Combination Lamps
- Front Turn Signal Lamps
 High Mount Stop Lamps
- Indirect Lighting
- Solid State Lighting and Signaling

Outline Drawings



Notes:

- 1. Dimensions are in millimeters (inches).
- 2. Dimensions without tolerances are nominal.
- Cathode lead is indicated with a "C" and anode lead is indicated with an "A."
- 4. Special characteristics are designated with a triangle.
- Clinch joint locations shown in dashed lines on top view of part (11.50 mm spacing).

Selection Guide

Part Number	LED COLOR	Total flux Φ_{V} (lm) @ 70 mA ^[1] Min.	Total Included angle $\theta_{0.90 \text{ V}}$ (Degrees) ⁽²⁾ Typ.
HPWT-TH00-00000 HPWT-FH00-00000	TS ALINGAP RED-ORANGE	3.0	120 70
HPWT-TL00-00000 HPWT-FL00-00000	TS ALINGAP AMBER	1.5	I 20 70

Absolute Maximum Ratings at $T_A = 25^{\circ}C$

Parameter	HPWT-TxOO/FxOO	Units	
DC FORWARD CURRENT ^[1,2] POWER DISSIPATION	70 22 I	мА мW	
Reverse Voltage ($I_R = 100 \mu_A$)	10	V	
Operating Temperature Range	-40 то + I 00	°C	
Storage Temperature Range	-55 то +IOO	°C	
High Temperature Chamber	25 (2 HRS.)	°C	
LED JUNCTION TEMPERATURE	125	°C	

Notes:

- 1. Φ_V is the total luminous flux output as measured with an integrating sphere after the device has stabilized (R θ_{j-a} = 200°C/W, T_A = 25°C).
- 2. $\theta_{0.90 V}$ is the included angle at which 90% of the total luminous flux is captured. See Figure 5.

Notes:

- 1. Operation at currents below 10 mA is not recommended.
- 2. Derate linearly as shown in Figure 3.

Optical Characteristics at T_{A} = 25°C, I_{F} = 70 mA, $R_{\rm \theta J-A}$ = 200°C/W

Device Type	Total flux Φ_v (lm) ^[1] Min.	Peak wavelength λρεακ (nm) Typ.	Color, Dominant Wavelength λ _d (nm) ^[2] Typ.	Total Included Angle $\theta_{0.90 V}$ (degrees) ^[3] Typ.	Ratio of Luminous Intensity to Total Flux $I_v(cd)/\Phi_v(lm)$ Typ.	Viewing Angle 20 1/2 (Degrees) Typ.
HPWT-TH HPWT-FH	100 3.C 100	630	621	l 20 70	0.6 2.0	85 30
HPWT-TL HPWT-FL	.00 I.5 .00	596	594	I 20 70	0.6 2.0	85 30

Notes:

- 1. Φ_v is the total luminous flux output as measured with an integrating sphere after the device has stabilized.
- 2. The dominant wavelength is derived from the CIE Chromaticity Diagram and represents the perceived color of the device.
- 3. $\theta_{aso v}$ is the included angle at which 90% of the total luminous flux is captured. See Figure 5.

Electrical Characteristics at $T_A = 25^{\circ}C$

	Forward Voltage V _f (Volts) @ I _f = 70 mA			$\begin{array}{l} \text{Reverse} \\ \text{Breakdown} \\ \text{V}_{\text{R}} \left(\text{Volts} \right) \\ \textcircled{0}{0} \text{I}_{\text{R}} = 1 \text{ 00} \\ \mu_{\text{A}} \end{array}$		Capacitance C (PF) $V_F = O,$ F = 1 MHz.	Thermal resistance Rθ _{j-pin} (°C/W)	Speed of Response t _s (ns) ^[1]
DEVICE TYPE	Μιν	Түр	Мах	Min.	Typ.	Typ.	Typ.	Typ.
HPWT-xHOO HPWT-xLOO	2.19 2.19	2.50 2.60	3.03 3.15	10 10	20 20	40 40	80 100	20 20

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Figures



Figure 1. Relative Intensity vs. Wavelength.



AMBIENT TEMPERATURE (C) Figure 3. HPWT-xx00 Maximum DC Forward Current vs. Ambient

Temperature.



Figure 4. HPWT-xx00 Relative Luminous Flux vs. Forward Current.



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HPWT-xL00

70

6

40

30

2

0 L 1.5

1.9 2.1 2.3 2.5 2.7 2.

FORWARD VOLTAGE (V)

FORWARD CURRENT (mA)

TOTAL INCLUDED ANGLE (DEGREES)

Figure 5. HPWT-xx00 Percent Total Luminous Flux vs. Total Included Angle.



Figure 6a. HPWT-Tx00 Relative Intensity vs. Off Axis Angle.



Figure 6b. HPWT-Fx00 Relative Intensity vs. Off Axis Angle.

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Company Information

SnapLED[™] is developed, manufactured and marketed by Lumileds Lighting, LLC. Lumileds is a world-class supplier of Light Emitting Diodes (LEDs) producing billions of LEDs annually. Lumileds is a fully integrated supplier, producing core LED material in all three base colors (Red, Green, Blue) and White. Lumileds has R&D development centers in San Jose, California and Best, The Netherlands and production capabilities in San Jose, California and Malaysia.

Lumileds is pioneering high-flux LED technology and bridging the gap between solid state LED technology and the lighting world. Lumileds is absolutely dedicated to bringing the best and brightest LED technology to enable new applications and markets in the lighting world.

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